

## N-Channel 60 V (D-S) 175 °C MOSFET

### DESCRIPTION

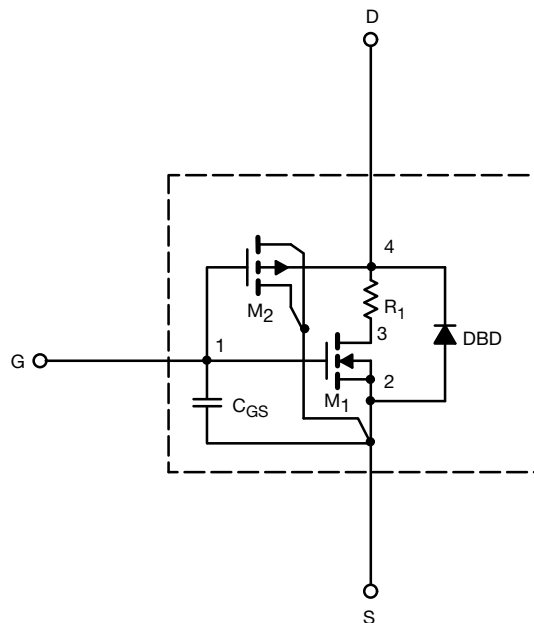
The attached SPICE model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the - 55 °C to 125 °C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched  $C_{gd}$  model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

### CHARACTERISTICS

- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the - 55 °C to + 125 °C Temperature Range
- Model the Gate Charge

### SUBCIRCUIT MODEL SCHEMATIC



### Note

- This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



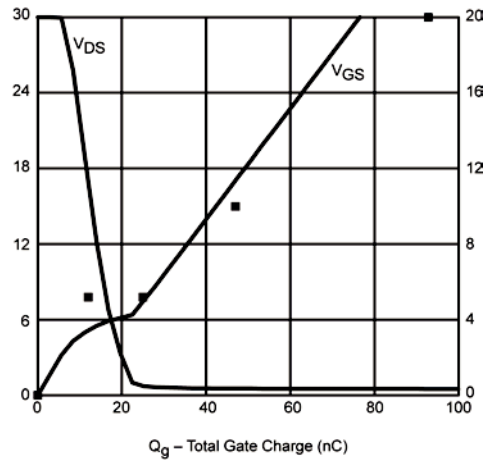
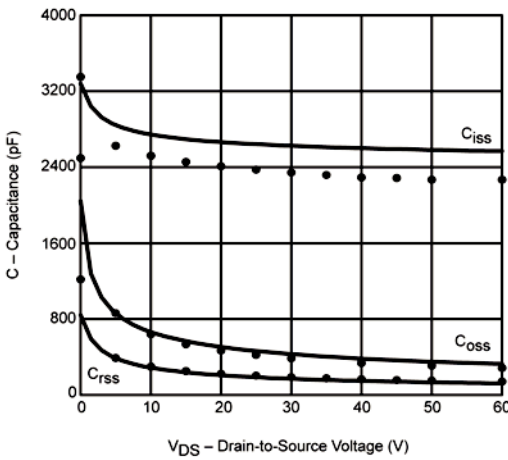
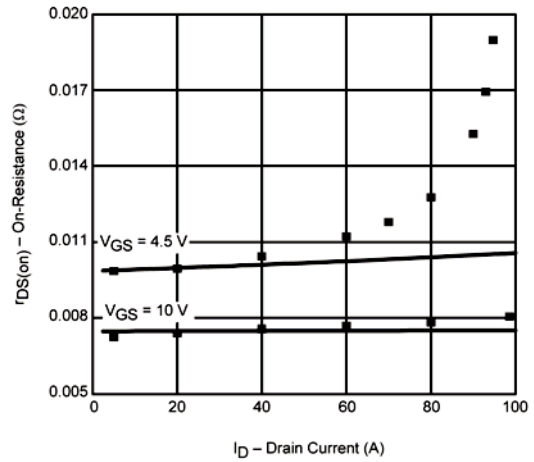
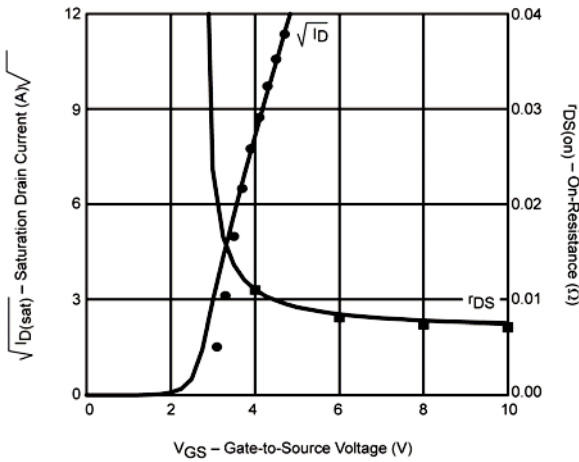
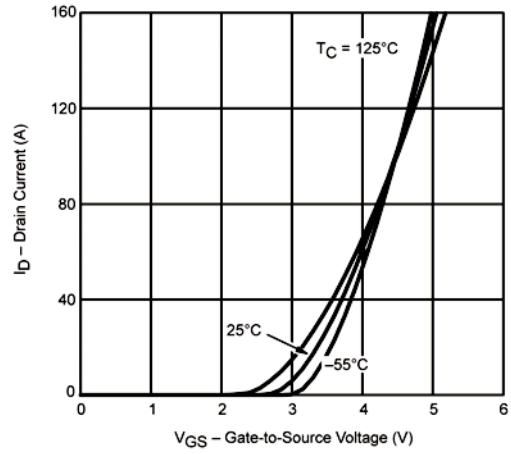
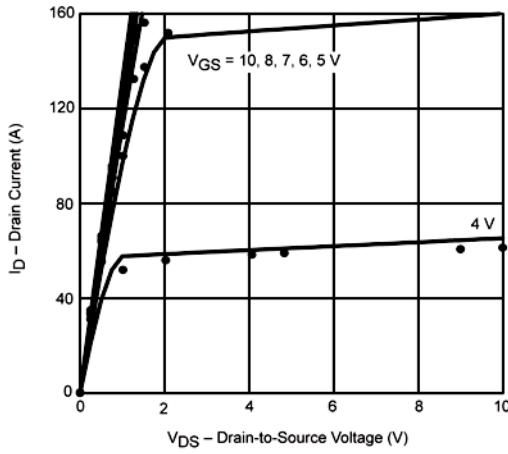
<b>SPECIFICATIONS</b> ( $T_J = 25\text{ }^\circ\text{C}$ , unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
<b>Static</b>					
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_D = 250\text{ }\mu\text{A}$	1.7	-	V
On-State Drain Current <sup>a</sup>	$I_{D(on)}$	$V_{DS} = 5\text{ V}$ , $V_{GS} = 10\text{ V}$	627	-	A
Drain-Source On-State Resistance <sup>a</sup>	$R_{DS(on)}$	$V_{GS} = 10\text{ V}$ , $I_D = 30\text{ A}$	0.0075	0.0075	$\Omega$
		$V_{GS} = 10\text{ V}$ , $I_D = 30\text{ A}$ , $T_J = 125\text{ }^\circ\text{C}$	0.0116	-	
		$V_{GS} = 10\text{ V}$ , $I_D = 30\text{ A}$ , $T_J = 175\text{ }^\circ\text{C}$	0.0138	-	
		$V_{GS} = 4.5\text{ V}$ , $I_D = 30\text{ A}$	0.0103	0.0105	
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	$I_F = 90\text{ A}$ , $V_{GS} = 0\text{ V}$	0.93	-	V
<b>Dynamic<sup>b</sup></b>					
Input Capacitance	$C_{iss}$	$V_{DS} = 25\text{ V}$ , $V_{GS} = 0\text{ V}$ , $f = 1\text{ MHz}$	2643	2400	pF
Output Capacitance	$C_{oss}$		460	430	
Reverse Transfer Capacitance	$C_{rss}$		186	210	
Total Gate Charge <sup>c</sup>	$Q_g$	$V_{DS} = 30\text{ V}$ , $V_{GS} = 10\text{ V}$ , $I_D = 90\text{ A}$	42	47	nC
Gate-Source Charge <sup>c</sup>	$Q_{gs}$		12	12	
Gate-Drain Charge <sup>c</sup>	$Q_{gd}$		13	13	
Turn-On Delay Time <sup>c</sup>	$t_{d(on)}$	$V_{DD} = 30\text{ V}$ , $R_L = 0.4\text{ }\Omega$ $I_D = 90\text{ A}$ , $V_{GEN} = 10\text{ V}$ , $R_g = 2.5\text{ }\Omega$	16	7	ns
Rise Time <sup>c</sup>	$t_r$		13	30	
Turn-Off Delay Time <sup>c</sup>	$t_{d(off)}$		25	25	
Fall Time <sup>c</sup>	$t_f$		21	12	

**Notes**

- Pulse test; pulse width  $\leq 300\text{ }\mu\text{s}$ , duty cycle  $\leq 2\%$ .
- Guaranteed by design, not subject to production testing.
- Independent of operating temperature.



**COMPARISON OF MODEL WITH MEASURED DATA** ( $T_J = 25\text{ }^\circ\text{C}$ , unless otherwise noted)



**Note**

- Dots and squares represent measured data.



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